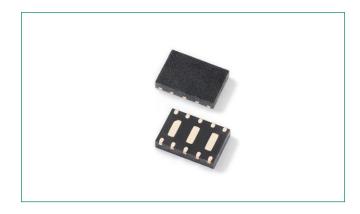


## SP3374NUTG 3.3V 40A Diode Array







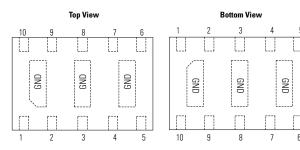


# **Description**

The SP3374NUTG is a low-capacitance, TVS Diode Array designed to provide protection against ESD (electrostatic discharge), CDE (cable discharge events), EFT (electrical fast transients), and lightning induced surges for high-speed, differential data lines. It's packaged in a µDFN package (3.0 x 2.0mm) and each device can protect up 4 channels or 2 differential pairs, up to 40A (IEC 61000-4-5 2nd edition,) and up to 30kV ESD (IEC 61000-4-2). The "flow-through" design minimizes signal distortion, reduces voltage overshoot, and provides a simplified PCB design.

The SP3374NUTG with its low capacitance and low clamping voltage makes it ideal for high-speed data interfaces such as 1GbE applications found in notebooks, switches, etc.

### **Pinout**



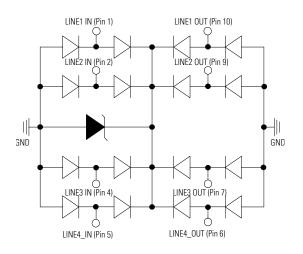
NOTE: PIN3. PIN8 are same potential with GND

### **Features**

- ESD, IEC 61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC 61000-4-4, 40A (5/50ns)
- Lightning, 40A (8/20µs as defined in IEC 61000-4-5 2nd Edition)
- Low capacitance of 3.5pF@0V (TYP) per I/O
- · Low leakage current of 0.1µA (TYP) at 3.3V

- µDFN-10 package is optimized for high-speed data line routing
- Provides protection for two differential data pairs (4 channels) up to 40A
- · Low operating and clamping voltage
- AEC-Q101 qualified
- Halogen free, Lead free and RoHS compliant

### **Functional Block Diagram**



Life Support Note:

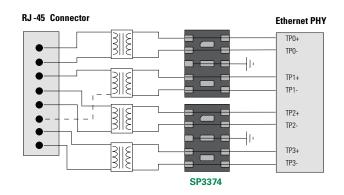
### Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

### **Applications**

- •10/100/1000 Ethernet
- WAN/LAN Equipment
- Desktops, Servers and Notebooks
- LVDS Interfaces
- Integrated Magnetics
- Smart TV

### **Application Example**



# TVS Diode Array (SPA®Diodes) Lightning Surge Protection - SP3374NUTG

### **Absolute Maximum Ratings**

Symbol	Parameter	Value	Units
l <sub>pp</sub>	Peak Current (t <sub>p</sub> =8/20µs)	40	А
P <sub>Pk</sub>	Peak Pulse Power (t <sub>p</sub> =8/20μs)	1000	W
T <sub>OP</sub>	Operating Temperature	-40 to 125	°C
T <sub>STOR</sub>	Storage Temperature	-55 to 150	°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

### Electrical Characteristics (T<sub>OP</sub>=25°C)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Reverse Standoff Voltage	V <sub>RWM</sub>	$I_R \le 1\mu A$			3.3	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 3.3V, T = 25°C		0.1	0.5	μΑ
Snap Back Voltage	V <sub>SB</sub>	I <sub>SB</sub> = 50mA	2.8			V
		$I_{pp} = 1A$ , $t_p = 8/20 \mu s$ Any I/O to Ground			5.5	V
		$I_{pp} = 10A$ , $t_p = 8/20 \mu s$ Any I/O to Ground			10.5	
Clamp Voltage	V <sub>c</sub>	$I_{pp}$ = 25A, $t_p$ = 8/20µs Any I/O to Ground			18.0	
		I <sub>pp</sub> = 40A, t <sub>p</sub> = 8/20μs Line-to-Line <sup>1</sup> , two I/O Pins connected together on each line			25.0	
Dynamic Resistance <sup>2</sup>	R <sub>DYN</sub>	TLP, t <sub>p</sub> =100ns, Any I/O to Ground		0.15		Ω
ESD Withstand Voltage V <sub>ESD</sub>	V	IEC 61000-4-2 (Contact)	±30			kV
	V <sub>ESD</sub>	IEC 61000-4-2 (Air)	±30			kV
	C <sub>I/O to GND</sub>	Between I/O Pins and Ground V <sub>R</sub> = 0V, f = 1MHz		3.5	5.0	pF
Diode Capacitance	C <sub>I/O to I/O</sub>	Between I/O Pins V <sub>B</sub> = 0V, f = 1MHz		1.7		pF

Notes:

1. Rating with 2 pins connected together per sugguested diagram ( For example, pin1 is connected to pin 10, pin 2 is connected to Pin 9, Pin 4 is connected to pin 7 and pin 5 is connected to pin 6)

2. Transmission Line Pulse (TLP) with 100ns width, 2ns rise time, and average window t1=70ns to t2=90ns



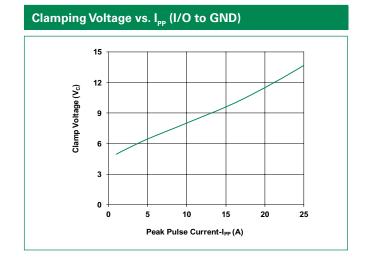
# 15.0 15.0 15.0 12.0 9.0 9.0 6.0 3.0

1.5

Bias Voltage (V)

2.5

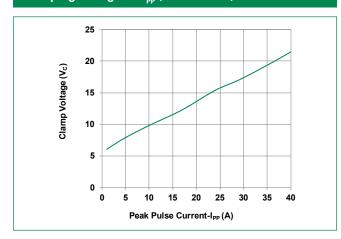
3.5



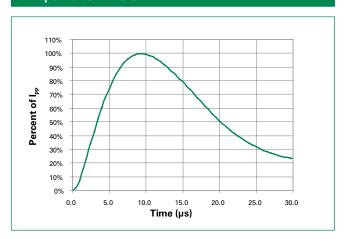
### Clamping Voltage vs. I<sub>PP</sub> (Line-to-Line)

0.5

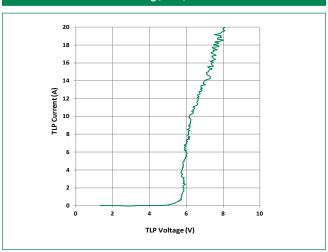
0.0



### 8/20µS Pulse Waveform

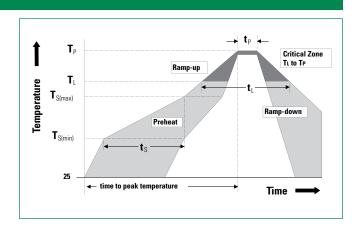


### Transmission Line Pulsing(TLP) Plot



### **Soldering Parameters**

Reflow Con	Pb – Free assembly		
	- Temperature Min (T <sub>s(min)</sub> )	150°C	
Pre Heat	-Temperature Max (T <sub>s(max)</sub> )	200°C	
	-Time (min to max) (t <sub>s</sub> )	60 - 180 secs	
Average ran	3°C/second max		
T <sub>S(max)</sub> to T <sub>L</sub> -	3°C/second max		
Reflow	- Temperature (T <sub>L</sub> ) (Liquidus)	217°C	
	- Temperature (t <sub>L</sub> )	60 – 150 seconds	
Peak Tempe	260 <sup>+0/-5</sup> °C		
Time within	20 - 40 seconds		
Ramp-down Rate		6°C/second max	
Time 25°C t	8 minutes Max.		
Do not exce	260°C		



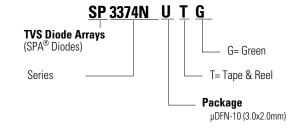
### **Ordering Information**

Part Number	Package	Min. Order Qty.
SP3374NUTG	μDFN-10 (3.0x2.0mm)	3000

### **Product Characteristics**

Lead Plating	Pre-Plated Frame
Lead Material	Copper Alloy
Substrate material	Silicon
Body Material	Molded Compound
Flammability	UL Recognized compound meeting flammability rating V-0

### **Part Numbering System**

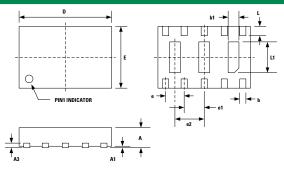


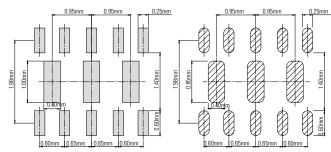
### **Part Marking System**

<u>b</u>G4



### Package Dimensions - µDFN-10 (3.0x2.0mm)



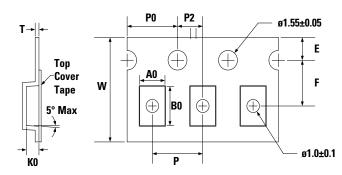


Recommended Soldering Pads Layout Recommended Stencil Apertures Recommended Stencil thickness 5mils

Package	μDFN-10 (3.0x2.0mm)						
JEDEC		MO-229					
Compleal		Millimeters		Inches			
Symbol	Min	Nom	Max	Min	Nom	Max	
Α	0.50	0.60	0.65	0.020	0.024	0.026	
A1	0.00	0.03	0.05	0.000	0.001	0.002	
А3		0.15 Ref		0.006 Ref			
b	0.15	0.20	0.25	0.006	0.008	0.010	
b1	0.25	0.35	0.45	0.010	0.014	0.018	
D	2.90	3.00	3.10	0.114	0.118	0.122	
E	1.90	2.00	2.10	0.075	0.079	0.083	
е		0.60 BSC 0.024 BSC					
e1	0.65 BSC			0	.026 BSC		
e2		0.95 BSC			0.037		
L	0.25	0.30	0.35	0.010	0.012	0.014	
L1	0.95	1.00	1.05	0.037	0.039	0.041	

- 1. All dimensions are in millimeters
- Dimensions include solder plating.
   Dimensions are exclusive of mold flash & metal burr.
- 4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
- 5. Package surface matte finish VDI 11-13.

### Tape & Reel Specification - µDFN-10 (3.0x2.0mm)



De	evice Orient	ation in Tap	e	
5	$\bigcirc$	$\bigcirc$		
Pin1 Location				

μDFN-10 (3.0x2.0mm)		
Millimeters		
2.30 +/- 0.10		
3.20 +/- 0.10		
1.75 +/- 0.10		
3.50 +/- 0.05		
1.0 +/- 0.10		
4.00 +/- 0.10		
4.00 +/- 0.10		
2.00 +/- 0.10		
0.3 +/- 0.05		
8.00 +0.30/- 0.10		